

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1-50. (Canceled)

51. (Previously Presented) A light emitting device comprising:
a light emitting layer comprising an organic material,
wherein said light emitting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

52. (Currently Amended) The light emitting device according to claim [[1]] 51 wherein said light emitting layer comprising tris-8-quinolinolate aluminum complex (Alq_3).

53. (Previously Presented) A light emitting device comprising:
a substrate;
an insulating film comprising silicon nitride over the substrate; and
a light emitting layer comprising an organic material formed over the insulating film,
wherein said light emitting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

54. (Currently Amended) The light emitting device according to claim [[3]] 53 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex (Alq_3).

55. (Currently Amended) The light emitting device according to claim [[3]] 53 further comprising a thin film transistor formed over the substrate and below said insulating film.

56. (Previously Presented) A light emitting device comprising:
a substrate;
an insulating film comprising silicon nitride over the substrate;
an anode formed on said insulating film;
a light emitting layer comprising an organic material formed over the anode; and
a cathode formed over the light emitting layer,
wherein said light emitting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

57. (Currently Amended) The light emitting device according to claim [[6]] 56 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex (Alq_3).

58. (Currently Amended) The light emitting device according to claim [[7]] 56 further comprising a thin film transistor formed over the substrate and electrically connected to said anode.

59. (Previously Presented) A light emitting device comprising:
a substrate;
a light emitting layer comprising an organic material formed over the substrate; and
an insulating film comprising carbon formed over the light emitting layer,
wherein said light emitting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

60. (Currently Amended) The light emitting device according to claim [[9]] 59 wherein said insulating film comprises diamond like carbon.

61. (Currently Amended) The light emitting device according to claim [[9]] 59 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex (Alq_3).

62. (Currently Amended) The light emitting device according to claim ~~[[9]]~~ 59 further comprising a thin film transistor formed over the substrate and electrically connected to said anode.

63. (Previously Presented) A light emitting device comprising:
a substrate;
an insulating film comprising silicon oxynitride over the substrate; and
a light emitting layer comprising an organic material formed over the insulating film,
wherein said light emitting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

64. (Currently Amended) The light emitting device according to claim ~~[[13]]~~ 63 wherein said light emitting layer comprises tris-8-quinolinolate aluminum complex (Alq_3).

65. (Currently Amended) The light emitting device according to claim ~~[[13]]~~ 64 further comprising a thin film transistor formed over the substrate and below said insulating film.

66. (Previously Presented) A light emitting device comprising:
a hole injecting layer comprising an organic material,
wherein said hole injecting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

67. (Currently Amended) The light emitting device according to claim ~~[[16]]~~ 66 wherein said organic material is phthalocyanine-based organic compound.

68. (Currently Amended) The light emitting device according to claim ~~[[16]]~~ 66 wherein said device is an active matrix type device.

69. (Currently Amended) A light emitting device comprising:
a hole transporting layer comprising an organic material,
wherein said hole ~~injecting~~ transporting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

70. (Currently Amended) The light emitting device according to claim ~~[[19]]~~ 69 wherein said organic material is aromatic amine-based organic compound.

71. (Currently Amended) The light emitting device according to claim ~~[[19]]~~ 69 wherein said device is an active matrix type device.

72. (New) A light emitting device comprising:
a electron injecting layer comprising an organic material,
wherein said electron injecting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

73. (New) The light emitting device according to claim 72 wherein said electron injecting layer is a metal complex.

74. (New) The light emitting device according to claim 73 wherein said electron injecting layer is tris-8-quinolinolate aluminum complex (Alq_3).

75. (New) The light emitting device according to claim 72 wherein said light emitting device is an active matrix type device.

76. (New) A light emitting device comprising:
a electron transporting layer comprising an organic material,

wherein said electron transporting layer contains oxygen at a concentration equal to or less than $1 \times 10^{19} \text{ cm}^{-3}$.

77. (New) The light emitting device according to claim 76 wherein said light emitting device is an active matrix type device.

78. (New) The light emitting device according to claim 67 wherein said hole injecting layer is copper phthalocyanine (CuPc).

79. (New) The light emitting device according to claim 70 wherein said hole transporting layer is at least one selected from the group consisting of 4, 4', 4''-tris (N-3-methylphenyl- N-phenylamino) -triphenylamine (MTDATA) and 4-4'-bis(N-(1-naphthyl)-N-phenylamino)-biphenyl (α -NPD).

80. (New) The light emitting device according to claim 51 wherein said light emitting device is an active matrix type device.

81. (New) The light emitting device according to claim 53 wherein said light emitting device is an active matrix type device.

82. (New) The light emitting device according to claim 56 wherein said light emitting device is an active matrix type device.

83. (New) The light emitting device according to claim 59 wherein said light emitting device is an active matrix type device.

84. (New) The light emitting device according to claim 63 wherein said light emitting device is an active matrix type device.